

Digital Transistors (Built-in Resistors)

DTA143XE/DTA143XUA

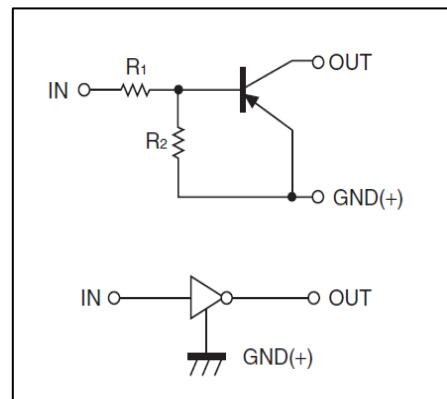
DTA143XKA/DTA143XCA

DIGITAL TRANSISTOR (PNP)

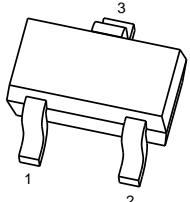
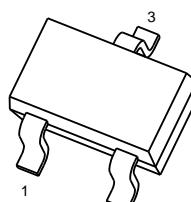
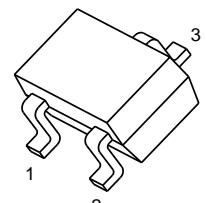
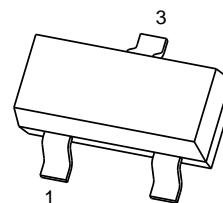
FEATURES

- Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see equivalent circuit)
- The bias resistors consist of thin-film resistors with complete isolation to allow positive biasing of the input. They also have the advantage of almost completely eliminating parasitic effects
- Only the on/off conditions need to be set for operation, making device design easy

• Equivalent Circuit



PIN CONNECTIONS and MARKING

DTA143XE	SOT-523	DTA143XUA	SOT-323
	1. IN 2. GND 3. OUT		1. IN 2. GND 3. OUT
MARKING:33		MARKING:33	
DTA143XKA	SOT-23-3L	DTA143XCA	SOT-23
	1. IN 2. GND 3. OUT		1. IN 2. GND 3. OUT
MARKING:33		MARKING:33	

MAXIMUM RATINGS(Ta=25°C unless otherwise noted)

Symbol	Parameter	Limits(DTA143X□)				Unit	
		E	UA	CA	KA		
V _{cc}	Supply Voltage	-50					
V _{IN}	Input Voltage	-20~+7					
I _O	Output Current	-100					
P _D	Power Dissipation	150	200	200	200	mW	
T _J , T _{stg}	Operation Junction and Storage Temperature Range	-55~+150					

ELECTRICAL CHARACTERISTICS (Ta=25°C unless otherwise specified)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Input voltage	V _{I(off)}	V _{cc} =-5V,I _O =-100μA	-0.3			V
	V _{I(on)}	V _O =-0.3V ,I _O =-20mA			-2.5	V
Output voltage	V _{O(on)}	I _O /I _I =-10mA/-0.5mA		-0.1	-0.3	V
Input current	I _I	V _I =-5V			-1.8	mA
Output current	I _{O(off)}	V _{cc} =-50V,V _I =0			-0.5	μA
DC current gain	G _I	V _O =-5V,I _O =-10mA	30			
Input resistance	R _I		3.29	4.7	6.11	kΩ
Resistance ratio	R ₂ /R ₁		1.7	2.1	2.6	
Transition frequency	f _T	V _O =-10V,I _O =-5mA,f=100MHz		250		MHz

Typical Characteristics

